PNP/NPN Epitaxial Planar Silicon Transistors



2SA1521/2SC3915

# Switching Applications (with Bias Resistance)

# Applications

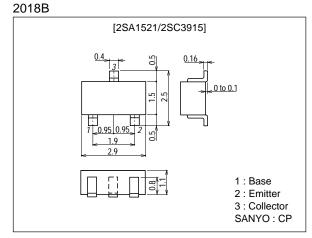
· Switching circuits, inverter circuits, interface circuits, dirver circuits.

# **Features**

- · On-chip bias resistance :  $R1=2.2k\Omega$ ,  $R2=2.2k\Omega$ .
- · Small-sized package : CP.
- · Large current capacity :  $I_C = 500 \text{mA}$ .

# **Package Dimensions**

unit:mm



(): 2SA1521

# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(–)50	V
Collector-to-Emitter Voltage	VCEO		(–)50	V
Emitter-to-Base Voltage	VEBO		(–)6	V
Collector Current	IC		(–)500	mA
Collector Current (Pulse)	ICP		(–)800	mA
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit	
			min	typ	max	Unit	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(–)0.1	μΑ	
	ICEO	V <sub>CE</sub> =(-)40V, I <sub>B</sub> =0			(–)0.5	μA	
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =(-)5V, I <sub>C</sub> =0	(–)860	(–) 1140	(–) 1670	μA	
DC Current Gain	hFE	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)50mA	50				
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)5mA		250		MHz	
				(200)		MHz	
Marking 2SA1521 : OL, 2SC3915 ; WY					Continued on next page.		

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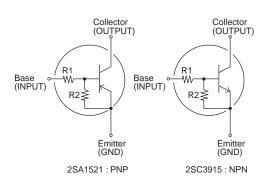
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

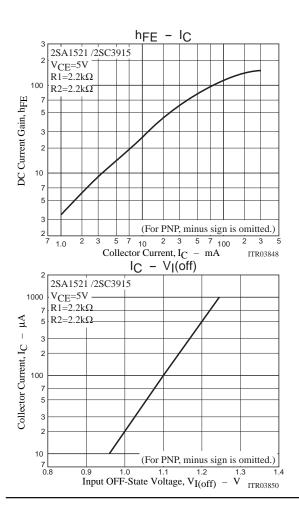
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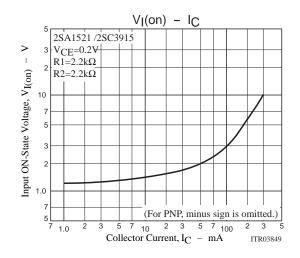
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Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Output Capacitance	<u> </u>	V <sub>CB</sub> =(-)10V, f=1MHz		3.7		pF
	Cob			(5.5)		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)50mA, I <sub>B</sub> =(-)2.5mA		(–)0.1	(–)0.3	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(–)50			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(−)100µA, R <sub>BE</sub> =∞	(–)50			V
Input OFF-State Voltage	V <sub>I(off)</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)100μA	(–)0.8	(–)1.1	(–)1.5	V
Input ON-State Voltage	V <sub>I(on)</sub>	V <sub>CE</sub> =(-)0.2V, I <sub>C</sub> =(-)50mA	(–)1.0	(–)1.9	(–)4.0	V
Input Resistance	R1		1.5	2.2	(–)2.9	kΩ
Resistance Ratio	R1/R2		0.9	1.0	(–)1.1	

## **Electrical Connection**







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